

# ST2600C..R SERIES

## PHASE CONTROL THYRISTORS

## Hockey Puk Version

### Features

- Double side cooling
- High surge capability
- High mean current
- Fatigue free

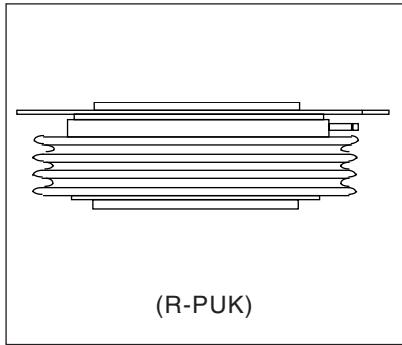
### Typical Applications

- DC motor controls
- Controlled DC power supplies
- AC controllers

### Major Ratings and Characteristics

Parameters	ST2600C..R	Units
$I_{T(AV)}$	2220	A
@ $T_C$	80	°C
$I_{T(AV)}$	2630	A
@ $T_{hs}$	55	°C
$I_{T(RMS)}$	4800	A
@ $T_{hs}$	25	°C
$I_{TSM}$	@ 50Hz	46000 A
	@ 60Hz	48200 A
$I^2t$	@ 50Hz	10580 KA <sup>2</sup> s
	@ 60Hz	9640 KA <sup>2</sup> s
$V_{DRM}/V_{RRM}$	2000 to 3000	V
$t_q$	typical	400 $\mu$ s
$T_J$	max.	125 °C

2630A



## ST2600C..R Series

Bulletin I25199 rev. B 02/00

International  
IR Rectifier

### ELECTRICAL SPECIFICATIONS

#### Voltage Ratings

Type number	Voltage Code	$V_{DRM}/V_{RRM}$ , max. repetitive peak and off-state voltage V	$V_{RSM}$ , maximum non-repetitive peak voltage V	$I_{DRM}/I_{RRM}$ max. @ $T_C = 125^\circ\text{C}$ mA
ST2600C..R	20	2000	2100	250
	22	2200	2300	
	24	2400	2500	
	26	2600	2700	
	28	2800	2900	
	30	3000	3100	

#### On-state Conduction

Parameter	ST2600C..R	Units	Conditions
$I_{T(AV)}$ Max. average on-state current @ Case temperature	2220 (1440) 80	A $^\circ\text{C}$	180° conduction, half sine wave double side (single side [anode side]) cooled
$I_{T(AV)}$ Max. average on-state current @ Heatsink temperature	2630 (1160) 55 (85)	A $^\circ\text{C}$	
$I_{T(RMS)}$ Max. RMS on-state current	4800	A	DC @ 25°C heatsink temperature double side cooled
$I_{TSM}$ Max. peak, one-cycle non-repetitive surge current	46000	A	t = 10ms No voltage
	48200		t = 8.3ms reapplied
	36800		t = 10ms 50% $V_{RRM}$
	38500		t = 8.3ms reapplied
$I^2t$ Maximum $I^2t$ for fusing	10580	KA <sup>2</sup> s	t = 10ms No voltage
	9640		t = 8.3ms reapplied
	6770		t = 10ms 50% $V_{RRM}$
	6150		t = 8.3ms reapplied
$V_{T(TO)}$ Max. value of threshold voltage	0.89	V	$T_J = T_J$ max.
$r_t$ Max. value of on-state slope resistance	0.19	m $\Omega$	$T_J = T_J$ max.
$V_{TM}$ Max. on-state voltage	1.45	V	$I_{pk} = 2900\text{A}$ , $T_C = 25^\circ\text{C}$
$I_L$ Max. (typical) latching current	300 (100)	mA	$T_J = 25^\circ\text{C}$ , $V_D = 5\text{V}$

#### Switching

Parameter	ST2600C..R	Units	Conditions
$di/dt$ Max. repetitive 50Hz (no repetitive) rate of rise of turned-on current	150 (300)	A/ $\mu\text{s}$	From 67% $V_{DRM}$ gate drive 20V, 20 $\Omega$ , $t_r = 1\mu\text{s}$ $T_J = T_J$ max.
$t_d$ Maximum delay time	2.0	$\mu\text{s}$	Gate drive 30V, 15 $\Omega$ , $V_d = 67\% V_{DRM}$ , $T_J = 25^\circ\text{C}$ Rise time 0.5 $\mu\text{s}$
$t_q$ Typical turn-off time	400		$I_T = 800\text{A}$ , $t_p = 1\text{ms}$ , $T_J = T_J$ max, $V_{RM} = 50\text{V}$ , $dI_{RR}/dt = 20\text{A}/\mu\text{s}$ , $V_{DR} = 67\% V_{DRM}$ , $dV/dt = 20\text{V}/\mu\text{s}$ linear

### Blocking

Parameter	ST2600C..R	Units	Conditions
dv/dt Maximum linear rate of rise of off-state voltage	500	V/ $\mu$ s	$T_J = T_J$ max. to 67% rated $V_{DRM}$
$I_{RRM}$ $I_{DRM}$ Max. peak reverse and off-state leakage current	250	mA	$T_J = 125^\circ\text{C}$ rated $V_{DRM}/V_{RRM}$ applied

### Triggering

Parameter	ST2600C..R	Units	Conditions
$P_{GM}$ Maximum peak gate power	150	W	$t_p = 100\mu\text{s}$
$P_{G(AV)}$ Maximum average gate power	10		
$I_{GM}$ Max. peak positive gate current	30	A	Anode positive with respect to cathode
$V_{GM}$ Max. peak positive gate voltage	30	V	Anode positive with respect to cathode
$-V_{GM}$ Max. peak negative gate voltage	0.25	V	Anode negative with respect to cathode
$I_{GT}$ Maximum DC gate current required to trigger	400	mA	$T_C = 25^\circ\text{C}$ , $V_{DRM} = 5V$
$V_{GT}$ Maximum gate voltage required to trigger	4	V	$T_C = 25^\circ\text{C}$ , $V_{DRM} = 5V$
$V_{GD}$ DC gate voltage not to trigger	0.25	V	$T_C = 125^\circ\text{C}$ Max. gate current/voltage not to trigger is the max. value which will not trigger any unit with rated $V_{DRM}$ anode-to-cathode applied

### Thermal and Mechanical Specification

Parameter	ST2600C..R	Units	Conditions
$T_J$ max. Max. operating temperature	125	$^\circ\text{C}$	On-state (conducting)
$T_{stg}$ Max. storage temperature range	-55 to 125		
$R_{thJ-C}$ Thermal resistance, junction to case	0.019 0.0095	K/W	DC operation single side cooled DC operation double side cooled
$R_{th(C-h)}$ Thermal resistance, case to heatsink	0.004 0.002	K/W	Single side cooled Double side cooled
F Mounting force $\pm 10\%$	43000 (4400)	N (Kg)	
wt Approximate weight	1600	g	
Case style	(R-PUK)		See Outline Table

### $\Delta R_{thJ-C}$ Conduction

(The following table shows the increment of thermal resistance  $R_{thJ-C}$  when devices operate at different conduction angles than DC)

Conduction angle	Single side	Double side	Units	Conditions
180°	0.0010	0.0010	K/W	$T_J = T_J$ max.
120°	0.0017	0.0017		
60°	0.0044	0.0044		

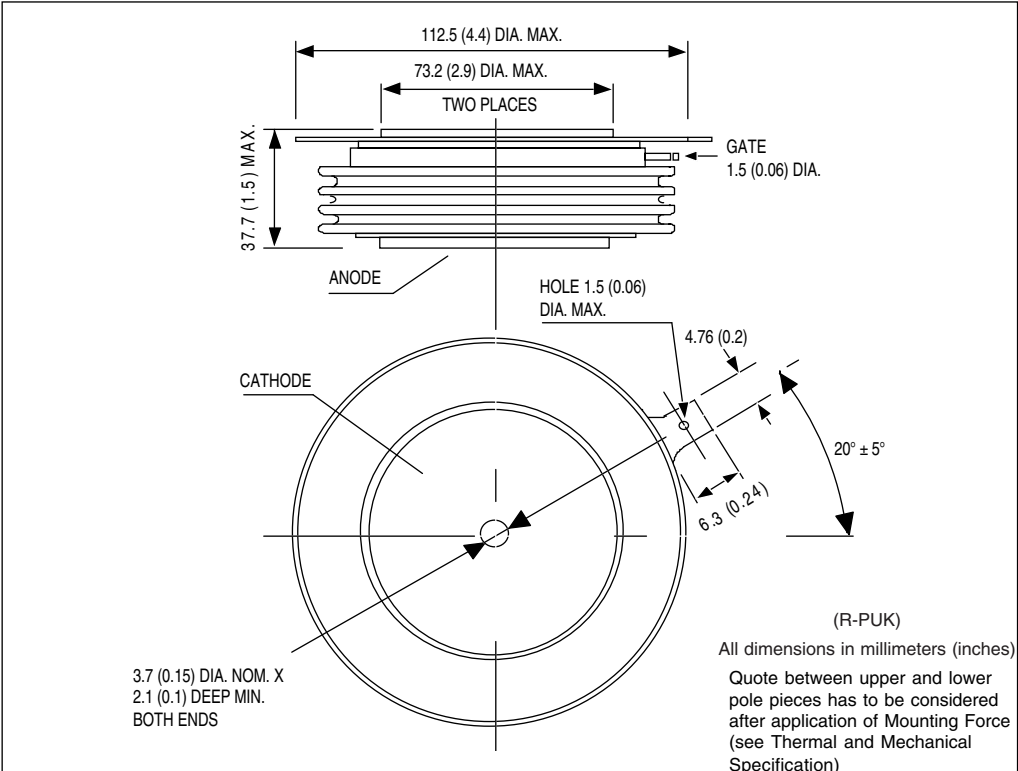
ST2600C..R Series

Bulletin I25199 rev. B 02/00

Ordering Information Table

Device Code							
1	2	3	4	5	6	7	8
ST	260	0	C	30	R	1	
1	- Thyristor						
2	- Essential part number						
3	- 0 = Converter grade						
4	- C = Ceramic Puk						
5	- Voltage code: Code x 100 = $V_{RRM}$ (See Voltage Rating Table)						
6	- R = Puk Case						
7	- 0 = Eyelet terminals (Gate and Auxiliary Cathode Unsoldered Leads)						
	1 = Fast-on terminals (Gate and Auxiliary Cathode Unsoldered Leads)						
	2 = Eyelet terminals (Gate and Auxiliary Cathode Soldered Leads)						
	3 = Fast-on terminals (Gate and Auxiliary Cathode Soldered Leads)						
8	- Critical dv/dt: None = 500V/ $\mu$ sec (Standard selection)						
	L = 1000V/ $\mu$ sec (Special selection)						

Outline Table



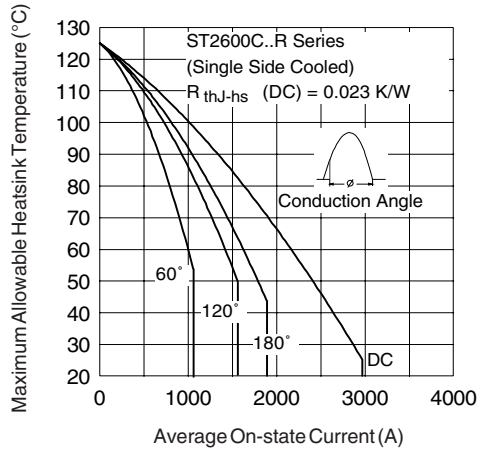


Fig. 1 - Current Ratings Characteristics

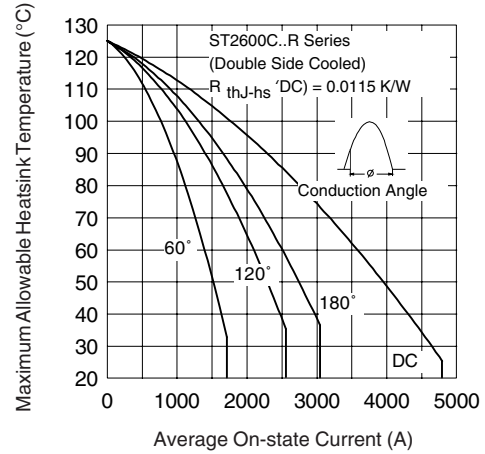


Fig. 2 - Current Ratings Characteristics

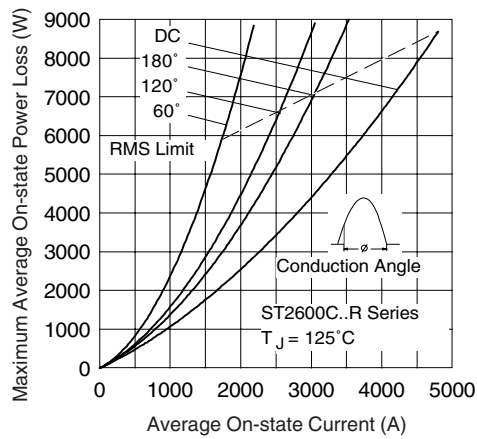


Fig. 3 - On-state Power Loss Characteristics

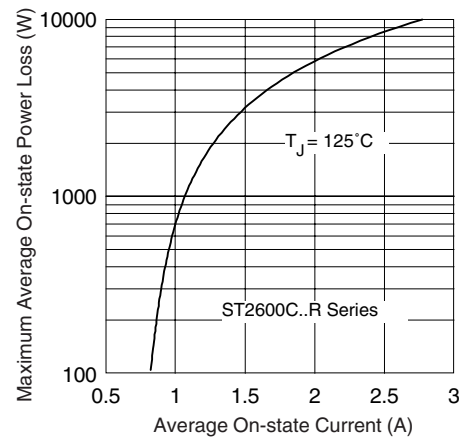


Fig. 4 - On-state Power Loss Characteristics

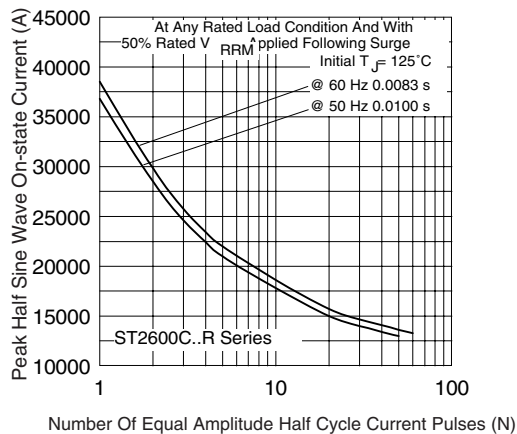


Fig. 5 - Maximum Non-Repetitive Surge Current  
Single and Double Side Cooled

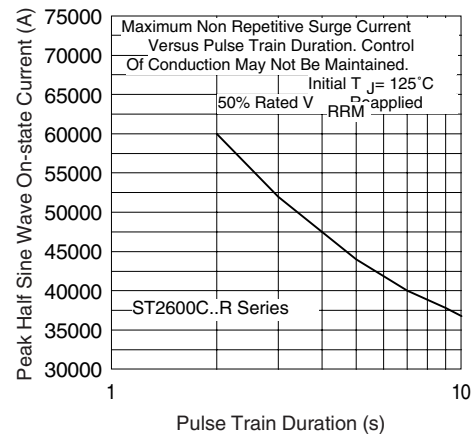


Fig. 6 - Maximum Non-Repetitive Surge Current  
Single and Double Side Cooled

